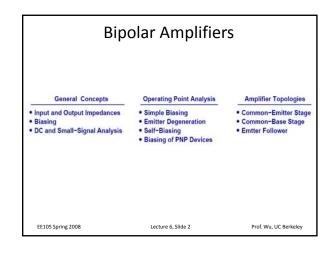
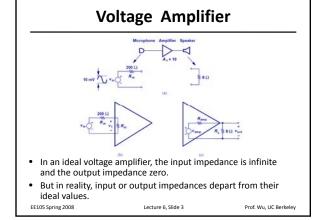
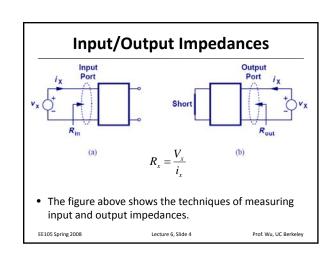
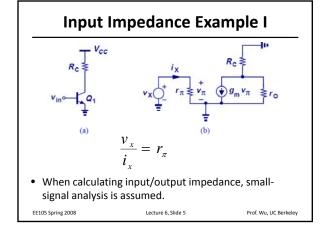
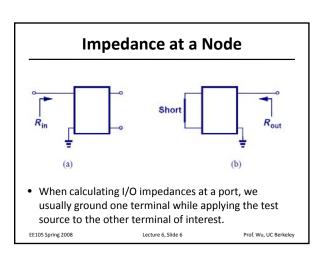
Lecture 6 OUTLINE • Bipolar Amplifiers - General considerations - Bias circuit and operating point analysis Reading: Chapter 5.1-5.2





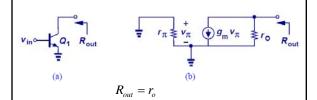






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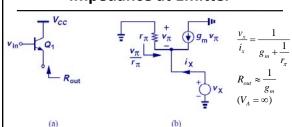
Impedance at Collector



• With Early effect, the impedance seen at the collector is equal to the intrinsic output impedance of the transistor (if emitter is grounded).

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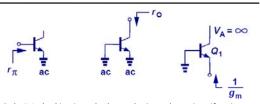
Impedance at Emitter



 The impedance seen at the emitter of a transistor is approximately equal to one over its transconductance (if the base is grounded).

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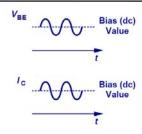
Three Master Rules of Transistor Impedances



- Rule # 1: looking into the base, the impedance is r_π if emitter is (ac) grounded.
- Rule # 2: looking into the collector, the impedance is r_o if emitter is (ac) grounded.
- Rule # 3: looking into the emitter, the impedance is 1/g_m if base is (ac) grounded and Early effect is neglected.

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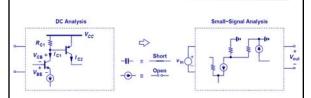
Biasing of BJT



 Transistors and circuits must be biased because (1) transistors must operate in the active region, (2) their small-signal parameters depend on the bias conditions.

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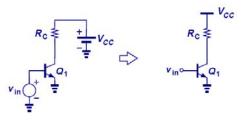
DC Analysis vs. Small-Signal Analysis



- First, DC analysis is performed to determine operating point and obtain small-signal parameters.
- Second, sources are set to zero and small-signal model is used.

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Notation Simplification



 Hereafter, the battery that supplies power to the circuit is replaced by a horizontal bar labeled V_{cc}, and input signal is simplified as one node called V_{in}.

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Example of Bad Biasing



- The microphone is connected to the amplifier in an attempt to amplify the small output signal of the microphone.
- Unfortunately, there's no DC bias current running through the transistor to set the transconductance.

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Another Example of Bad Biasing



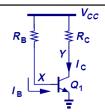
- The base of the amplifier is connected to V_{cc}, trying to establish a DC bias.
- Unfortunately, the output signal produced by the microphone is shorted to the power supply.

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Biasing with Base Resistor



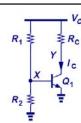
$$I_{B} = \frac{V_{CC} - V_{BE}}{R_{B}}$$

$$I_{C} = \beta \left(\frac{V_{CC} - V_{BE}}{R_{B}}\right)$$

- Assuming a constant value for V_{BE}, one can solve for both I_B and I_C and determine the terminal voltages of the transistor.
- However, bias point is sensitive to β variations.

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Improved Biasing: Resistive Divider



$$R_{c}$$
 $V_{x} = \frac{R_{2}}{R_{1} + R_{2}} V_{CC}$
 I_{c}
 $I_{C} = I_{S} \exp(\frac{R_{2}}{R_{1} + R_{2}} \frac{V_{CC}}{V_{T}})$

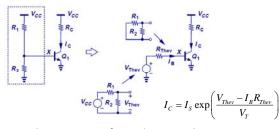
 Using resistor divider to set V_{BE}, it is possible to produce an I_C that is relatively independent of β if base current is small.

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Accounting for Base Current



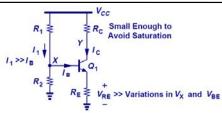
 With proper ratio of R₁ and R₂, I_C can be insensitive to β; however, its exponential dependence on resistor deviations makes it less useful.

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Emitter Degeneration Biasing



- The presence of R_E helps to absorb the error in V_X so V_{BE} stays relatively constant.
- This bias technique is less sensitive to β (I $_{_1}>>$ I $_{_B})$ and V $_{_{\rm RF}}$ variations.

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Design Procedure

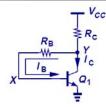
- Choose an I_C to provide the necessary small signal parameters, g_m , r_π , etc.
- Considering the variations of R₁, R₂, and V_{BE}, choose a value for V_{RE} .
- With V_{RE} chosen, and V_{BE} calculated, V_{x} can be determined.
- Select R₁ and R₂ to provide V_x

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Self-Biasing Technique



- This bias technique utilizes the collector voltage to provide the necessary V_x and I_B .
- One important characteristic of this technique is that collector has a higher potential than the base, thus guaranteeing active operation of the transistor.

Self-Biasing Design Guidelines

(1)
$$R_C >> \frac{R_B}{\beta}$$

(2) $\Delta V_{BE} << V_{CC} - V_{BE}$

(2)
$$\Delta V_{RE} \ll V_{CC} - V_{RE}$$

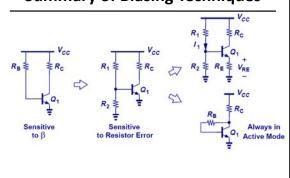
- (1) provides insensitivity to β .
- (2) provides insensitivity to variation in VBE.

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Summary of Biasing Techniques

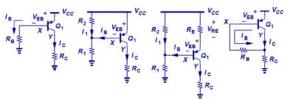


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PNP Biasing Techniques



• Same principles that apply to NPN biasing also apply to PNP biasing with only polarity modifications.

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